15 A, 600 V Hyperfast Rectifier

RHRG1560CC-F085



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TO-247-3LD CASE 340CK

MARKING DIAGRAM

\$Y&Z&3&K RHRG1560C

RHRG1560C = Specific Device Code \$Y = ON Semiconductor Logo &Z = Assembly Lot Code &3 = Numeric Date Code &K = Assembly Location

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

Max Ratings (600 V, 15 A)

The RHRG1560CC–F085 is an Hyperfast diode with soft recovery characteristics (t_{rr} < 55 ns). It has half the recovery time of ultrafast diode and is of silicon nitride passivated ion–implanted epitaxial planar construction. This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of automotive switching power supplies and other power switching automotive applications.

Its low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistors.

Features

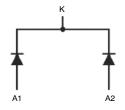
- High Speed Switching ($t_{rr} = 26 \text{ ns(Typ.)} @ I_F = 15 \text{ A}$)
- Low Forward Voltage ($V_F = 1.86 \text{ V(Typ.)} @ I_F = 15 \text{ A}$)
- Avalanche Energy Rated
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Switching Power Supply
- Power Switching Circuits
- Automotive and General Purpose

PIN ASSIGNMENTS





ABSOLUTE MAXIMUM RATINGS ($T_C = 25^{\circ}C$ Unless Otherwise Noted)

Symbol	Symbol Parameter		Units
V _{RRM}	Peak Repetitive Reverse Voltage		V
V _{RWM}	V _{RWM} Working Peak Reverse Voltage		V
V _R	V _R DC Blocking Voltage I _{F(AV)} Average Rectified Forward Current @ T _C = 25°C I _{FSM} Non-repetitive Peak Surge Current (Halfwave 1 Phase 50 Hz)		V
I _{F(AV)}			Α
I _{FSM}			Α
E _{AVL}	Avalanche Energy (1 A, 40 mH)	20	mJ
T _J , T _{STG}	Operating Junction and Storage Temperature	– 55 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS (T_C = 25°C Unless Otherwise Noted)

Symbol	Symbol Parameter		Units
Rejc	Maximum Thermal Resistance, Junction to Case	1.37	°C/W
RеJA	Maximum Thermal Resistance, Junction to Ambient	45	°C/W

PACKAGE MARKING AND ORDIRING INFORMATION

Device Marking	Device	Package	Tube	Quantity
RHRG1560C	RHRG1560CC-F085	TO-247	-	30

ELECTRICAL CHARACTERISTICS (T_C = 25°C Unless Otherwise Noted)

Symbol	Parameter	er Conditions		Min.	Тур.	Max	Units
I _R	Instantaneous Reverse Current	V _R = 600 V	T _C = 25°C	_	-	100	μА
			T _C = 175°C	_	-	1000	μА
V _{FM} (Note 1)	Instantaneous Forward Voltage	I _F = 15 A	$T_{C} = 25^{\circ}C$ $T_{C} = 175^{\circ}C$	- -	1.86 1.28	2.3 1.6	V V
t _{rr} (Note 2)	Reverse Recovery Time	$I_F = 1 \text{ A, di/dt} = 100 \text{ A/}\mu\text{s, V}_{CC} = 390 \text{ V}$	T _C = 25°C	_	25	50	ns
(14010 2)		I _F =15 A, di/dt = 100 A/μs, V _{CC} = 390 V	$T_{C} = 25^{\circ}C$ $T_{C} = 175^{\circ}C$	-	26 137	55 -	ns ns
t _a t _b	Reverse Recovery Time	I _F =15 A, di/dt = 100 A/μs, V _{CC} = 390 V	T _C = 25°C		15 11	-	ns ns
Q_{rr}	Reverse Recovery Charge			_	21	_	nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- 1. Pulse : Test Pulse width = 300 μ s, Duty Cycle = 2%.
- 2. Guaranteed by design.

TEST CIRCUIT AND WAVEFORMS

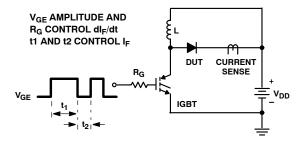


Figure 1. t_{rr} Test Circuit

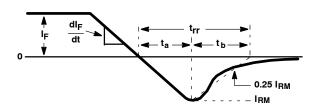
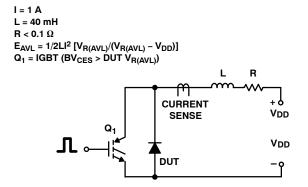


Figure 2. t_{rr} Waveforms and Definitions





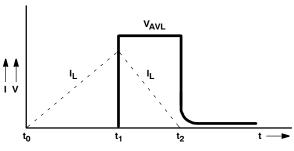


Figure 4. Avalanche Current and Voltage Waveforms

TYPICAL PERFORMANCE CHARACTERISTICS

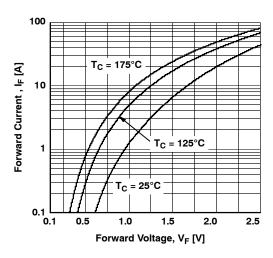


Figure 5. Typical Forward Voltage Drop vs. Forward Current

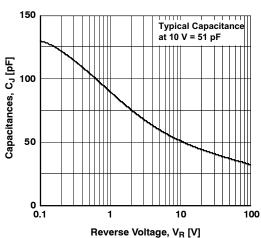


Figure 7. Typical Junction Capacitance

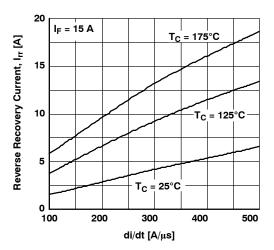


Figure 9. Typical Reverse Recovery Current vs. di/dt

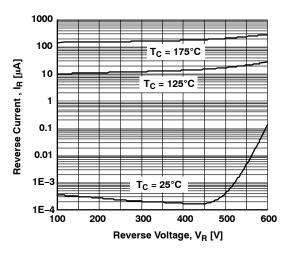


Figure 6. Typical Reverse Current vs. Reverse Voltage

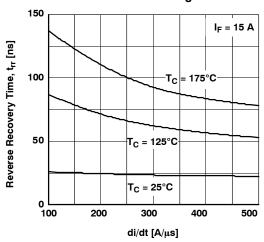


Figure 8. Typical Reverse Recovery Time vs. di/dt

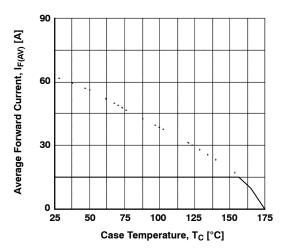


Figure 10. Forward Current Derating Curve

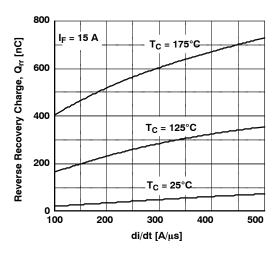


Figure 11. Reverse Recovery Charge

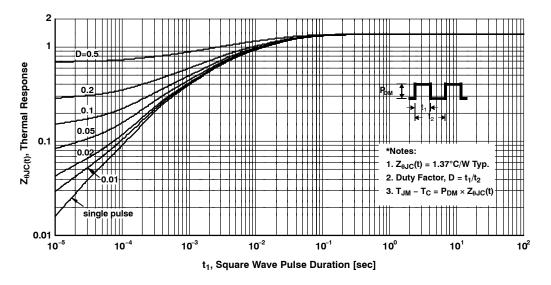
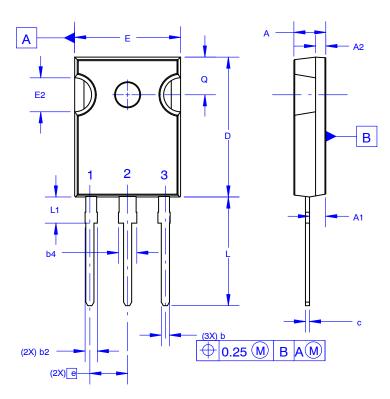


Figure 12. Transient Thermal Response Curve

TO-247-3LD SHORT LEAD

CASE 340CK ISSUE A





- A. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DRAWING CONFORMS TO ASME Y14.5 2009.
- D. DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED BY L1.
- E. LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY L1.

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code

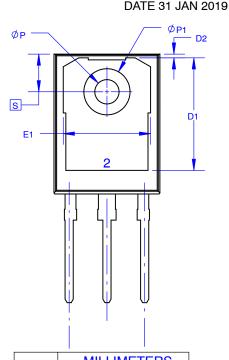
A = Assembly Location

Y = Year

WW = Work Week

ZZ = Assembly Lot Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



DIM	MILLIMETERS				
DIIVI	MIN	NOM	MAX		
Α	4.58	4.70	4.82		
A1	2.20	2.40	2.60		
A2	1.40	1.50	1.60		
b	1.17	1.26	1.35		
b2	1.53	1.65	1.77		
b4	2.42	2.54	2.66		
С	0.51	0.61	0.71		
D	20.32	20.57	20.82		
D1	13.08	~	~		
D2	0.51	0.93	1.35		
E	15.37	15.62	15.87		
E1	12.81	~	~		
E2	4.96	5.08	5.20		
е	~	5.56	~		
L	15.75	16.00	16.25		
L1	3.69	3.81	3.93		
ØΡ	3.51	3.58	3.65		
Ø P1	6.60	6.80	7.00		
Q	5.34	5.46	5.58		
S	5.34	5.46	5.58		

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ACGRB207-HF CLH03(TE16L,Q) ACGRC307-HF ACEFC304-HF NTE6356 NTE6359 NTE6002 NTE6023 NTE6039 NTE6077
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